

#### **DESCRIPTION:**

The P0102BL SCR provides high dv/dt rate with strong resistance to electromagnetic interface. They are especially recommended for use on residual current circuit breaker, straight hair, igniter etc.

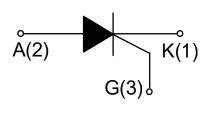


SOT-23-3

SOT-89

### **MAIN FEATURES**

Symbol	Value	Unit
I <sub>T(RMS)</sub>	0.8	А
lgт	≤200	μA



### **ABSOLUTE MAXIMUM RATINGS**

Para	Symbol	Value	Unit	
Storage junction temperature range		T <sub>stg</sub>	-40-150	$^{\circ}$
Operating junction temperature range		Tj	-40-125 <sup>1</sup>	$^{\circ}$ C
Repetitive peak off-state voltage		V <sub>DRM</sub>	600	V
Repetitive peak reverse voltage		V <sub>RRM</sub>	600	V
RMS on-state current	SOT-23-3L (Tc=40°C)	I <sub>T(RMS)</sub> 0.8		
	SOT-89-2L(Tc=70°C)		0.8	А
	SOT-223-2L (Tc=90°C)			
Non repetitive surge peak on-state current (F=50Hz tp=10ms)		I <sub>TSM</sub>	8	Α
Non repetitive surge peak on-state current (F=60Hz tp=8.3ms)		I <sub>TSM</sub>	9	Α
I <sup>2</sup> t value for fusing (tp=10ms)		l <sup>2</sup> t	0.32	A <sup>2</sup> s
Critical rate of rise of on-state current		dl/dt	50	A/µs
Peak gate current (tp=20µs, T <sub>j</sub> =125℃)		I <sub>GM</sub>	0.2	Α
Peak gate power (tp=20µs, T <sub>j</sub> =125℃)		Рсм	0.5	W
Average gate power dissipation(T <sub>j</sub> =125°C)		P <sub>G(AV)</sub>	0.1	W

**NOTE 1:** When we parallel connect a  $\leq 1K\Omega$  resistor between Gate and Cathode, the Tj can reach  $125^{\circ}$ C; if without this resistor, the Tj only can reach  $110^{\circ}$ C.



# **ELECTRICAL CHARACTERISTICS** ( $T_j$ =25 $^{\circ}$ C unless otherwise specified)

Symbol	Toot Condition	Value			lloit
	Test Condition	MIN.	TYP.	MAX.	Unit
lgт	V <sub>D</sub> =12V R <sub>L</sub> =33Ω	20	50	200	μA
V <sub>G</sub> T	VD-12V KL-3312	-	0.6	0.8	V
V <sub>GD</sub>	V <sub>D</sub> =V <sub>DRM</sub> T <sub>j</sub> =125℃	0.2	-	-	V
IL	I <sub>G</sub> =1.2 I <sub>GT</sub>	-	-	4	mA
Ін	I <sub>T</sub> =0.05A	-	-	3	mA
dV/dt	V <sub>D</sub> =400V T <sub>j</sub> =125°C R <sub>GK</sub> =1KΩ	600	-	-	V/µs
dV/dt	$V_D$ =400V $T_j$ =125°C $R_{GK}$ =220 $\Omega$	1000	-	-	V/µs
t <sub>on</sub>	I <sub>G</sub> =10mA I <sub>A</sub> =4mA I <sub>R</sub> =0.4mA	-	2	-	μs
t <sub>off</sub>	T <sub>j</sub> =25℃	-	50	-	μs
Rd	Dynamic Resistance T <sub>j</sub> =125℃	-	-	35	mΩ

## **STATIC CHARACTERISTICS**

Symbol	Parameter		Value(MAX)	Unit
V <sub>TM</sub>	I <sub>T</sub> =1.1A tp=380μs	Tj=25℃	1.5	V
I <sub>DRM</sub>	VD=VDRM VR=VRRM	T <sub>j</sub> =25℃	5	μA
I <sub>RRM</sub>		T <sub>j</sub> =125℃	100	μΑ

## **THERMAL RESISTANCES**

Symbol	Parameter		Value	Unit
Rth(j-c)	junction to case	SOT-23-3L	75	
		SOT-89-2L	45	°C/W
		SOT-223-2L	31	
R <sub>th(j-a)</sub>	junction to ambient	SOT-23-3L	125	
		SOT-89-2L	90	°C/W
		SOT-223-2L	60	



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**FIG.1** Maximum power dissipation versus RMS on-state current

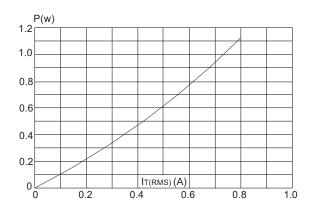
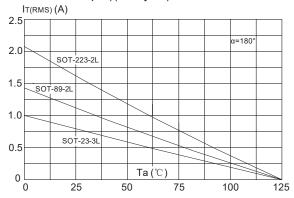
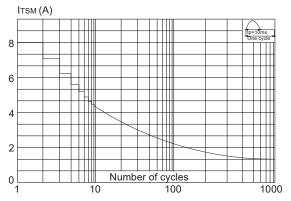


FIG.2: RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness:35µm)(full cycle)

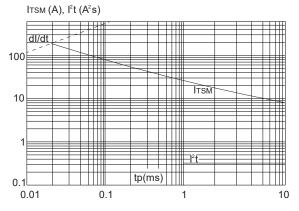




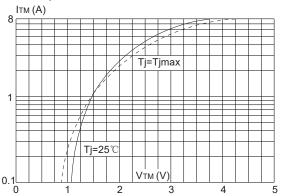
**FIG.3:** Surge peak on-state current versus number of cycles



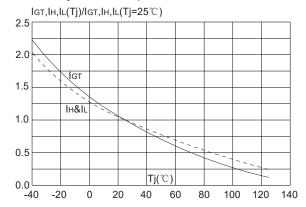
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp<10ms, and corresponging value of  $I^2t$  (dI/dt < 50A/ $\mu$ s)



**FIG.4:** On-state characteristics (maximum values)



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature





## **SOLDERING PARAMETERS**

Reflow Condition		Pb-Free assembly	
		(see figure at right)	
	-Temperature Min	+150℃	
	(T <sub>s(min)</sub> )	+130 C	
Pre	-Temperature Max	+200℃	
Heat	(T <sub>s(max)</sub> )	+200 C	
	-Time (Min to Max)	60 100 200	
	(ts)	60-180 secs.	
Average ramp up rate		3℃/sec. Max	
(Liquidus Temp (T <sub>L</sub> )to peak)		3 C/Sec. Max	
T <sub>s(max)</sub> to T <sub>L</sub> - Ramp-up Rate		3℃/sec. Max	
	-Temperature(T <sub>L</sub> )	+217℃	
Reflow	(Liquidus)	1217 C	
	-Temperature(t∟)	60-150 secs.	
Peak Temp (T <sub>p</sub> )		<b>+260(+0/-5)</b> ℃	
Time within 5℃of actual		20, 40	
Peak Temp (t <sub>p</sub> )		20-40secs.	
Ramp-down Rate		6℃/sec. Max	
Time 25℃ to Peak Temp (T <sub>P</sub> )		8 min. Max	
Do not exceed		+260℃	

